



Article **Redox Chemistry of the Subphases of α-CsPbI₂Br and** β-CsPbI₂Br: Theory Reveals New Potential for Photostability

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Abstract: The logic in the design of a halide-mixed $APb(I_{1-x}Br_x)_3$ perovskite is quite straightforward: to combine the superior photovoltaic qualities of iodine-based perovskites with the increased stability of bromine-based perovskites. However, even small amounts of Br doped into the iodine-based materials leads to some instability. In the present report, using first-principles computations, we analyzed a wide variety of α -CsPbI₂Br and β -CsPbI₂Br phases, compared their mixing enthalpies, explored their oxidative properties, and calculated their hole-coupled and hole-free charged Frenkel defect (CFD) formations by considering all possible channels of oxidation. Nanoinclusions of brominerich phases in α-CsPbI₂Br were shown to destabilize the material by inducing lattice strain, making it more susceptible to oxidation. The uniformly mixed phase of α -CsPbI₂Br was shown to be highly susceptible towards a phase transformation into β -CsPbI₂Br when halide interstitial or halide vacancy defects were introduced into the lattice. The rotation of PbI₄Br₂ octahedra in α -CsPbI₂Br allows it either to transform into a highly unstable apical β -CsPbI₂Br, which may phase-segregate and is susceptible to CFD, or to phase-transform into equatorial β-CsPbI₂Br, which is resilient against the deleterious effects of hole oxidation (energies of oxidation >0 eV) and demixing (energy of mixing <0 eV). Thus, the selective preparation of equatorial β -CsPbI₂Br offers an opportunity to obtain a mixed perovskite material with enhanced photostability and an intermediate bandgap between its constituent perovskites.

Keywords: density functional theory; inorganic perovskite solar cells; mixed perovskite solar cells; photovoltaics; redox chemistry; nanoinclusions

1. Introduction

Lead-based perovskite solar cells are currently a very actively studied and rapidly evolving area of materials science research [1]. The scientific community's interest in perovskites is largely due to their rapidly improving solar power conversion efficiencies (PCEs), which are now being reported to be as high as 25% [2]. In terms of PCE, this means that certified single-junction perovskite technology is comparable to the traditional state-of-the-art crystalline silicon photovoltaics (PV). Such an extraordinary performance is related to the low rate of radiative bimolecular recombination [3], long carrier lifetimes and large carrier lengths. It should be noted that the PCE directly correlates with the charge-carrier lifetime of the material. Unfortunately, the high PCEs of lead-based perovskites typically only last a few thousand hours [4–6], after which they degrade via a variety of mechanisms.

Paradoxically, perovskite materials are also highly defect-tolerant, particularly to the dominant neutral Schottky defects which are known to be plentiful in the bulk of the material [7]; however, these defects generally create shallow traps in the band gap while also being the source of ionic disorder. Defects which do act as traps appear to often



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Copyright: © 2023 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). not be as problematic as calculations would suggest; for example, the dangling bonds present on a undercoordinated lead after a Br vacancy is introduced into CsPbBr₃ exhibit a dynamic, oscillating behavior at the picosecond timescale. This is indicative of the fact that phonon–electron coupling can detrap the carriers despite the presence of a deep trap [8]. The soft, flexible nature of the material is responsible for rapid structural fluctuations which allow the local band structure to dynamically change, which consequently greatly slows recombination and leads to an increased carrier diffusion length [9]. In the case of organic–inorganic perovskites (MAPbX₃ and FAPbX₃), this seems to be related to the counter cations, which, while not being directly responsible for band gap behavior, screen carriers from being trapped or recombined [10], and thus the theoretical analysis of these materials is consequently more challenging; notably, heterostructures, in particular, show promise in this regard [11].

It would appear that defects by themselves do not degrade the material's PV properties, but rather it is the accumulation of deep traps at the surfaces, grains and interfaces that should be analyzed more closely. It should be noted that the perovskite PV stacks go through some degradation even when rationally engineered and well-encapsulated to prevent them from being degraded by environmental factors [12], which directly evidences the importance of preventing the photodegradation of the material. In the case of "pristine" materials based on a single halide, the tendency for the material to photodegrade has a few proposed explanations including the inherent volatility of the organic cations [13], surface-based degradation due to an accumulation of vacancy defects [14] and self-oxidation via charged Frenkel vacancy–halogen interstitial pairs generated by the coupling of carriers with the perovskite lattice [15].

An important observation pertaining to perovskites is the fact that the halide vacancy concentration increases dramatically upon illumination [15–17]. This leads to an increased ionic conductivity (σ_{ion}) upon illumination. This observation has been proposed to be caused by an oxidative reaction involving the coupling of a hole carrier with an iodine site. The iodine moves into the interstitial site and leaves it as a charged vacancy:

$$I_{I}^{x} + h^{\bullet} \to I_{i}^{x} + V_{I}^{\bullet}$$
⁽¹⁾

Such a localized charge-redistribution process is mediated by a small hole polaron and is likely the most common type of charged Frenkel defect (CFD). It is notable that hole polarons tend to have a significantly lower binding energy than the electron polarons and tend to be more localized in nature [10]. Theoretical work has suggested that self-trapping defects leading to localized halogen dimers (V centers, commonly called color centers [18]) may lead to the formation of highly mobile self-trapped excitons [19]. Theoretical studies suggest that shallow trapping is dominant in bulk while deep hole polarons are energetically expensive to generate [20]. The formation of I_2^- at high interstitial [21] concentrations has been suggested to occur at high hole concentrations [19] by such a mechanism:

$$I_{\rm I}^{\rm x} + 2h^{\bullet} \to I_{\rm i}^{\bullet} + V_{\rm I}^{\bullet} \tag{2}$$

Charge loss at surfaces and interfaces seems to be particularly problematic for the stability of the material [22]. Particularly, redox chemistry at the surface can lead to the formation of more hole polarons, which can then penetrate back into the material to cause the formation of more Frenkel defects by mechanism (1) creating a self-propagating loop of photodegradation. We note that it is also possible for Frenkel defects to form in a charge-balanced way, which creates an I'_i/V^{\bullet}_I pair.

In our recent paper [23], we described the effects of these deleterious CFDs arising from redox chemistry in the material migrating to the surface. In particular, the formation of the halide vacancy was associated with the creation of a metallic Pb-rich phase and the formation of the interstitial iodine was associated with the production of triiodide I_3^- , a superhalogen [24,25]. The mixed surface, having a higher work function and a lower iodine concentration, ought to have inhibited the formation of triiodide; however, halide-mixed perovskite materials offer an additional challenge to overcome: they phasesegregate upon illumination via the so-called "Hoke Effect" [26]. In the experimental part of the work [23], we found that the recombination of the Pb⁰ and I₃⁻ defects at the interfaces of the material led to the dominance of the CsPbI₃ phase at the grain boundary, thus negating the potential advantages of the mixed CsPbI₂Br material. Our density functional theory (DFT) calculations, however, left some questions open, since we did not observe a noticeably large difference in the favorability of CFD formation for iodine-based defects versus bromine-based defects in α -CsPbI₂Br, which led us to conclude that a more thorough analysis of the topic was necessary. It should be noted that a unified theory for light-induced segregation in mixed halides has recently been proposed [27] and supported by experimental evidence [28]. The theory indicates that light segregation ought to be less favorable for smaller cell values (Cs < MA, FA) and that CsPbI₂Br should be stable in its mixed form since calculations indicate that CsPb(I_{1-x}Br_x)₃ ought to be stable up to x = 0.43 at room temperature and 1 sun of illumination. This supports our expectation that CFDs may be the primary cause of instability for CsPbI₂Br.

The free energy of mixing of a mixed perovskite, while being an extremely important property, is not sufficient to fully describe the photostability, since there are materials, such as CsPbI₂Br, which ought to be photostable, but which segregate anyways. This motivates our current report, where we study the connection between the electronic structure of the perovskite, the geometrical features, and the stability towards photodegradation for pure cubic CsPbI₃, the halide-mixed black phase α -CsPbI₂Br [29] and β -CsPbI₂Br [30]. It should be noted that the cubic phase of CsPbI₃, while experimentally unstable at room temperature in its bulk phase [31], may be stabilized in quantum dots [32] and also serves as a good reference point for comparison for CsPbI₂Br as well as a relatively simple and robust model since we do not have to consider the orientation of the organic cation, which can greatly change the calculated defect formation energies in perovskite materials [33,34]. CsPbI₂Br has been noted for its superior thermodynamic stability [35] and is also somewhat closer to the ideal Goldschmidt tolerance when compared to CsPbI₃ [29] because of improved phase stability. For photovoltaic applications, α -CsPbI₂Br and β -CsPbI₂Br are prospective and recent experimental work has demonstrated the possibility of stabilizing α -CsPbI₂Br via dilute FeCl₂ incorporation [36]. Previous calculations have demonstrated that CsPbI₂Br exhibits a *p*-type behavior due to the high formation energies of donor defects [29], and in the Br-poor phase, it exhibits a Fermi pinning of the Br interstitial defects to the halide vacancy. Meanwhile, surface-based calculations have shown that acceptor interstitial halide defects have very low formation energies, and the donor vacancies are generally quite unfavorable to form [37]. Presently, we focus on understanding the destructive effects of holes on the mixed inorganic perovskite material.

2. Materials and Methods

We performed DFT simulations using the Vienna Ab initio Simulation Package (VASP) [38]. We utilized the PBE generalized gradient approximation (GGA) [39], a D3 dispersion correction [40] and the projector augmented-wave (PAW) pseudopotentials [41,42]. All our calculations had an energy cutoff of 600 eV. This combination of functional and dispersion correction has previously been shown to provide very good agreement with the experimental lattice constants of CsPbI₃ and RbPbI₃ and also showed good agreement with the magnitude of the band gap without spin–orbit corrections due to error cancellation [43]. We also included nonspherical contributions to the gradient inside of the PAW spheres. This correction has recently been reported to change the energy by as much as 30 meV/f.u. for perovskite oxides [44].

The cubic CsPbI₃ and CsPbI₂Br unit cells were optimized and then used to build $3 \times 3 \times 3$ supercells with the Atomic Simulation Environment (ASE) Python tools. In the case of CsPbI₃, we also built a $4 \times 4 \times 4$ supercell to investigate the effects of the supercell size. For the $3 \times 3 \times 3$ supercells, we used k-grids of $3 \times 3 \times 3$ and in the case of $4 \times 4 \times 4$ supercells we used $2 \times 2 \times 2$ sampling of the k-space. To ensure the sufficiency of this

method, we tested the $3 \times 3 \times 3$ supercell with $5 \times 5 \times 5$ sampling of the k-space and found that the pristine-cell oxidation energy (Equation (3)) changed by less than 0.01 eV. In the unit cell cases, we used $6 \times 6 \times 6$ k-grids or better. We allowed both the atomic positions and cell dimensions to relax without constraints, and also recalculated some of the hole-coupled oxidations with the MGGA functional HSE06 [45] to crosscheck our results. Previous calculations indicated that our PBE+D3 method was a reasonable compromise for calculating defect formation energies [46].

To compare the oxidative ability of each system we used the expression:

$$\Delta E_{ox} = \Delta E + q(E_F + E_{VBM}) + E_{corr}$$
(3)

$$\Delta \mathbf{E} = E(D^q) - E(D^0) \tag{4}$$

where $E(D^0)$ indicates the energy of the neutral slab and $E(D^q)$ indicates the energy of the charged slab. E_{VBM} was extracted from band structure calculations at the kpoint corresponding to the direct band gap E_g , the k-path of the band structure was determined with the help of AFLOW [47]. Finally, E_F is the Fermi energy, which may vary from 0 to E_g , and E_{corr} is the electrostatic correction. The simplest electrostatic correction is the Makov–Payne correction (the 1st order):

$$E^q = \frac{q^2 \alpha}{2\varepsilon L} \tag{5}$$

where α is the Madelung constant, ε is the dielectric constant of the pristine bulk and L is the lattice constant. This relatively basic charge-corrective method has recently been demonstrated to show good convergence versus the supercell size [48] in the case of MAPI, which was attributed to the highly screened nature of perovskites. It is notable that the Lany–Zunger correction (multiplying Makov–Payne E^q by 0.65) provides even better convergence versus the supercell size; therefore, we used it in our calculations where appropriate. Contrary to hybrid perovskites, the dielectric constant of Cs-based perovskites does not show a strong temperature-dependence [49]; as such, we used the measured effective dielectric constants of 8.6 [50] for CsPbI₂Br and 10 for α -CsPbI₃ [51]. In the text any time we mention an atom X in a chemical formula we imply a halogen I or Br.

3. Results and Discussion

3.1. Lattice Constants

To test the validity of our methodology against experimental data, we calculated the lattice constants of cubic and tetragonal-phase CsPbI₃ and CsPbI₂Br. For consistency, we used normalized lattice constants as in reference [52]; in the case of tetragonal phases, this was done by rotating the coordinate system in such a way that the a and b vectors were aligned along the Pb-X bonds. The lattice constants we calculated for α -CsPbI₃ and β -CsPbI₃ were generally in good agreement with experimental data and previous calculations (Table 1). In the case of pseudocubic α -CsPbI₂Br, we used α -CsPbI₃ Pm $\overline{3}m$ as the starting point; that is, replacing an iodine with a bromine yielded α -CsPbI₂Br P4/mmm, which, according to our calculations, was the most stable pseudocubic phase.

By doubling the α -CsPbI₃ *Pm3m* cell along all three directions, we were able to take into consideration more possible α -CsPbI₂Br phases. *Inma* was equally stable to *P4/mmm* and was then energetically followed by *Cm* and *Pmm2* (Figure 1). To obtain the "clusterized" *C1* phase, we considered a 3 × 3 × 3 supercell and made I -> Br substitutions in a localized section of the supercell (Figure 2), and the least stable α -CsPbI₂Br phase was *Amm2*. It is notable that $a = b \neq c$ in the case of α -CsPbI₂Br as the Pb-Br bond lengths were shorter than the Pb-I ones and thus a truly cubic phase was not possible to maintain. The main feature which distinguished pseudocubic α -CsPbI₂Br from β -CsPbI₂Br was that in the latter, the PbX₆ octahedra were rotated with respect to one another. Octahedral rotations are associated with soft phonon modes [53] and these modes, along with their anharmonic behavior [52], are responsible for black phase instability in CsPbI₃ at lower temperatures [54]. It is interesting to note that for pseudocubic structures, the average lattice parameter was nearly the same for all phases and only the spread of the values greatly differed. Notably, the *I*4/*mcm* phase had the largest spread with a = b = 6.31 Å and c = 5.93 Å.



Figure 1. The crystal structures of the α -CsPbI₃ $Pm\overline{3}m$ (blue box) and α -CsPbI₂Br P4/*mmm* (red box) phases, and all other α -CsPbI₂Br phases considered. The perspective is down the *c*-axis of the crystals with the lead atoms eclipsed by halides to better represent the halide substitutions.



Figure 2. The crystal $3 \times 3 \times 3$ supercells of the α -CsPbI₂Br *P4/mmm* (left) and α -CsPbI₂Br *C1* (right) phases.

In the case of β -CsPbI₂Br, we started with β -CsPbI₃ *I*4/*mcm* and substituted iodines for bromines in a variety of ways (Figure 3). Due to the presence of octahedral tilting, it

was possible to define apical and equatorial substitutions in the cell, which corresponded to *I4/mcm* and *Fmmm*, respectively. The latter has previously [55] been predicted to be more stable by 58 meV per formula unit, and our results were in concordance with their result. Thus, our results indicated that *Fmmm* was the most stable phase and *I4/mcm* was the least stable by 70 meV/f.u. Meanwhile, the "mixed" low-symmetry C2 phase was energetically in between them and 40 meV/f.u. less stable than *Fmmm*.

Table 1. Normalized lattice constants (Å) of various experimentally measured and theoretically simulated α -CsPbI3 β -CsPbI3, α -CsPbI2Br and β -CsPbI2Br phases. Values obtained in this work are in italics, values inside of round parentheses were computed with spin–orbit coupling included. Note that for α phases, only the a lattice parameter is represented while for β phases, the a and b parameters are shown.

	Phase	Lattice Parameter a		Energy/f.u. (eV/cell)
Exp	α -CsPbI ₃	6.29 [31], 6.297 [52]		-
DF1	a-CsPbI ₃ Pm3m	6.18 [52], 6.26 [56], 6.27 (6.30), 6.41 [57]		-15.28
Exp	α -CsPbI ₂ Br	6.138 [30]		_
	α -CsPbI ₂ Br P4/mmm	$6.18~(6.17)\pm0.22,6.26~[29]$		-15.84
	α-CsPbI ₂ Br C1	6.19 ± 0.02		-15.82
DFT	α -CsPbI ₂ Br Inma			-15.84
	α -CsPbI ₂ Br Cm	6.18 ± 0.13		-15.83
	α -CsPbI ₂ Br Pmm2	6.19 ± 0.04		-15.82
	α-CsPbI ₂ Br Amm2	6.19 ± 0.05		-15.80
	Phase	Lattice Parameters		Energy/f.u.
	rnase	а	b	(eV/cell)
Exp	β-CsPbI ₃	6.241 [52]	6.299 [52]	-
DFT	β -CsPbI ₃ I4/mcm	5.97 [52], 6.28	6.273 [52], 6.33	-15.30
Exp	β-CsPbI ₂ Br	6.130 [30]	6.088 [30]	-
	β-CsPbI ₂ Br I4/mcm	6.33 [29], 6.29	6.03 [29], 5.96	-15.84
DFT	β-CsPbI ₂ Br Fmmm	6.08 [55], 6.01 (6.03)	6.45 [55], 6.38 (6.37)	-15.92
	β -CsPbI ₂ Br C2	6.14	6.19	-15.87

To compare the most stable mixed alpha and beta phases in more detail, we calculated the deviation of α -CsPbI₂Br and β -CsPbI₂Br from Vegard's law. This was done by linearly projecting the lattice constants versus the Br concentration with the appropriately phased CsPbI₃ and CsPbBr₃ as the "end points". In the case of α -CsPbI₂Br, we noted a small average Vegard's deviation of just -0.02 Å. We also calculated the deviation with spinorbit coupling (SOC) included and found that it was -0.01 Å. In the case of β -CsPbI₂Br *Fmmm*, the deviation was much larger, being 0.14 Å for a = b and -0.16 Å for c. This deviation changed to 0.11 Å and -0.18 Å, respectively, when SOC was turned on. The limited effected of SOC on perovskite geometry has previously been observed in other works [46]. These deviations mean that the c-axis is too elongated when compared to Vegard's law, which implies a weakening of the Pb-I apical bond, whereas the equatorial plane is much more compact than one would expect, implying a stronger bonding in this plane. When analyzing the geometrical differences of β -CsPbI₂Br *Fmmm* with the respective pristine tetragonal phases of β -CsPbI₃ and β -CsPbBr₃ *I4/mcm*, we noted that the octahedral rotations were much larger for β -CsPbI₂Br *Fmmm* than for β -CsPbI₃ or β -CsPbBr₃ *I4/mcm*. Moreover, the Pb-I bond length on the apical positions was 0.03 Å longer than for β -CsPbI₃ *I4/mcm*. The major deviation from Vegard's law can be noted via visual inspection in Figure 4, where we compare Fmmm to the corresponding CsPbI₃ and CsPbI₃ β -phases when looking down the c-axis. The differences were quite notable: the latter two had an equatorial Pb-X-Pb angle of 165.8° whereas the former decreased to

157.9° showing a significantly larger rotation of the PbX₆ octahedra. Finally, we noted that the rotation of α -CsPbI₂Br *P4/mmm* into β -CsPbI₂Br *I4/mcm* energetically cost practically nothing since our method predicted only 0.002 eV/halide anion difference; it appears that the same was true for a transformation of α -CsPbI₂Br *P4/mmm* into β -CsPbI₂Br *Fmmm*; thus, it is questionable if such a phase shift can be selective.



Figure 3. The crystal structures of the β -CsPbI₃ *I4/mcm* (blue box) and β -CsPbI₂Br F*mmm* (red box) phases and all other β -CsPbI₂Br phases considered. The perspective is down the *c*-axis of the crystals with the lead atoms eclipsed by halides to better represent the halide substitutions. In this case, the system of coordinates was also rotated so that a and b became aligned with Pb-X bonds for easy comparison to Figure 1.

3.2. Mechanical Properties

Given the curious geometrical trends observed in the previous section, we considered the bulk modulus of α -*CsPbI*_x*Br*_{3-x} (x = 0, 1, 3) by way of calculating the energetic response to strain and fitting the results to the Birch–Murnaghan equation of state (EOS), shown below in Equation (6) in the E vs. V formulation:

$$E(V) = E_{\circ} + \frac{9 \times B_{\circ} V_{\circ}}{16} \left(\left(\left(\frac{V_{\circ}}{V} \right)^{\frac{2}{3}} - 1 \right)^{3} \times B_{\circ}' + \left(\left(\left(\frac{V_{\circ}}{V} \right)^{\frac{2}{3}} - 1 \right)^{2} \times \left(6 - 4 \times \left(\frac{V_{\circ}}{V} \right)^{\frac{2}{3}} \right) \right) \right)$$
(6)

where *E* is the energy, E_{\circ} is the equilibrium energy, *V* is the volume, V_{\circ} is the equilibrium volume, and B_{\circ} and B'_{\circ} refer, respectively, to the invariant and linear response of the bulk modulus; *B* is related to pressure *P*, as described below in Equation (7):

$$B = B_{\circ} + B_{\circ}' \times P \tag{7}$$

where *P* is typically taken to be 1 atm. The results (Figure S1 of Supplementary Information) tabulated in Table 2 show that a higher I concentration resulted in a lower bulk modulus. The ambient bulk modulus (B'_{\circ}) was relatively proportionate to the amount of Br; a one-third doping ratio of Br resulted in around 27% of the overall increase of B'_{\circ} . Previously, contrasting results were found for MAPbX₃ (X = Br, I) where the iodine-based perovskite

exhibited a 1.9 GPa higher bulk modulus at 15.0 GPa when compared to the bromine-based perovskite; that implied that the A cation size significantly influenced the trend [58]. For the case of Cs in the A sites, the bulk modulus was as high as 18.0 GPa for the I in the X site, which was 4.3 GPa lower than in the Br case. This is in line with other studies also employing the Birch–Murnaghan EOS, which found $B_{\circ} = 20.7$ GPa and $B'_{\circ} = 4.881$ for cubic CsPbBr₃ [59] ($B_{\circ} = 9.618$ for the surface of CsPbBr₃ [60]), and $B_{\circ} = 17.82$ GPa and $B'_{\circ} = 4.665$ for cubic CsPbI₃ [61]. The examination of the invariant and linear response variables showed that higher iodine concentrations resulted in a higher pressure-invariant component of the bulk modulus; however, notably, the pure I and Br cases had comparable linear response components, which were both nearly 0.2 lower than those for CsPbI₂Br. While the effect at ambient pressures was not enough to overcome that of the invariant term, these calculations indicate that at higher pressures, the mixed halogens will exhibit a lower strain response than the pure perovskites.



Figure 4. A view down the c-axis of the β phases of CsPbI₃, CsPbI₂Br (*I4/mcm* and *Fmmm*) and CsPbBr₃. The colored squares indicate the equatorial planes of the PbX₆ octahedra for easier comparison.

	B_{\circ} (GPa)	$m{B}_{\circ}^{\prime}$	<i>R</i> ²
α-CsPbBr ₃ Pm3m	22.31	4.67	0.99997
α-CsPbI ₂ Br P4/mmm	19.20	4.85	1.00000
α -CsPbI ₃ Pm $\overline{3}m$	18.04	4.67	0.99996

Table 2. Fitted zero- (B_{\circ}) and first-order (B'_{\circ} , dimensionless) portions of the bulk modulus (B) from the energy vs. volume response curve fit to the Birch–Murnaghan equation of state.

3.3. Mixing Energy

Since the free-energy of cubic $CsPb(I_{1-x}Br_x)_3$ was investigated quite thoroughly previously [34], we focused our attention, as in the lattice constant section, on the distinctions between α -CsPbI2Br and β -CsPbI2Br.

The mixing energy is defined as:

$$\Delta U_{M}(CsPb(I_{1-x}Br_{x})_{3}) = \frac{E(CsPb(I_{1-x}Br_{x})_{3}) - (1-x)E(CsPbI_{3}) - x * E(CsPbBr_{3})}{N}$$
(8)

where $E(CsPb(I_{1-x}Br_x)_3)$ is the energy of a $CsPb(I_{1-x}Br_x)_3$ configuration and $E(CsPbI_3)$ and $E(CsPbBr_3)$ are the energies of pure cesium–lead–iodide and cesium–lead–bromide perovskites, respectively, in the appropriate phases; N is the number of anion halides per CsPbI₂Br cell. We chose to use this unit to keep our units consistent with previous results [62] for MAPbBr_xI_{(1-x}). Figure 5a presents ΔU_M for all the phases considered in Section 3.1. In the case of both the alpha and beta phases, we used the same phases of pure perovskites when calculating the mixing energy. Generally, we noted a significantly higher mixing energy of α -CsPb($I_{1-x}Br_x$)₃, which indicated that β -CsPb($I_{1-x}Br_x$)₃ would generally have better miscibility for all values of x.

When considering the effects of configurational entropy, we refer to Section 3.1 and note that the α -CsPbI₂Br in fact had two dominant motifs in its unit cells: one with three halide sites and another with six, whereas, for β -CsPbI₂Br, only twelve appeared. Therefore, the difference in stability was even greater than Figure 5a would suggest; we plotted these contributions in Figure 5b. It is natural to question that perhaps it could be possible to stabilize this mixed perovskite by modifying the experimental conditions to selectively prepare β -CsPbI₂Br, which would be much less miscible; however, as we show in the next section, the redox chemistry is equally important to consider before making any such conclusions.

3.4. Redox Properties of α -CsPbI₂Br and β -CsPbI₂Br

In this section, we consider the redox properties of α -CsPbI₃, α -CsPbI₂Br *P4/mmm*, α -CsPbI₂Br *C1*, β -CsPbI₂Br *I4/mcm* and β -CsPbI₂Br *Fmmm*. By applying Equation (4), one may judge the oxidative capability of the materials. For the sake of consistency, we list them at E_f = 0 eV for oxidation and E_f = E_g for reduction (Table 3). Just as in the case of the molecular I₂ and Br₂ species, there was a very notable difference between CsPbI₃ and CsPbBr₃: the latter was significantly harder to oxidize at E_F = 0 eV. Surprisingly, the oxidative capability of CsPbI₂Br differed very little from that of CsPbI₃ in all phases except for β -CsPbI₂Br *Fmmm*, which was more resilient than the other mixed phases. Adding an electrostatic correction did not essentially change the patterns observed. For completeness, we also list the Fermi pinning energy of the pristine material and its energy of oxidation (or reduction since they are equal at the pinning E_F). We note that such donors and acceptors may also couple to band-edge carriers; thus, the quantities considered in Table 3 are those relating ed to free carriers (independent of chemical potentials) [63]. The fact that the energy of oxidation of the pristine material did not change very much by a doping of 33% of bromine was somewhat unexpected. This is apparently related to the fact that the iodine

and bromine atoms are well separated near valence-p-contributions in the partial density of states (DOS) (Figures 6 and S2–S8 of SI). Thus, the iodine sites are oxidized preferentially over the bromine sites. An increase in the bromine content causes the spectroscopic Br *p*-contribution to grow, but at the same time the bandgap also widens, and oxidation of the mixed material ought to become less favorable. Thus, two phases emerge; namely, the Br-rich mixed perovskite bulk and iodine-rich nanoinclusions; the latter outcompetes the former in the generation of carriers by virtue of having a smaller E_g. This simple description is in line with the unified theory of light segregation [27].



Figure 5. (a) The mixing energies ΔU_M of all the phases calculated. The room temperature solid solution approximation $\Omega x(1 - x) \Omega = 0.06 - 0.02x$ (orange line) and the approximation for a completely random alloy in the high temperature limit (black line) are also plotted; (b) The configurational entropy depending on the number of halide sites in the unit cell.

Table 3. Energies of oxidation and reduction at $E_F = 0$ and $E_F = E_g$, respectively, as well as the energy of oxidation or reduction at the pristine Fermi pinning energy E_{pin}^* . For the former three, we included Lany–Zunger corrected values in parentheses. The valence band maximum EVBM and direct band gap energy are also included. The * distinguishes these oxidation energies from the Frenkel oxidation energies of future tables.

	$E_{ox} *$ ($I_I^x + h^{\bullet} \rightarrow I_I^{\bullet}$) @EF =0 (eV)	$ E_{red} * (I_I^x + e' \rightarrow I_I') @ $		E _{pin} * (eV)	E _{VBM} (eV)	Eg (eV)
α -CsPbI ₃ Pm $\overline{3}m$	0.25 (0.34)	0.08 (0.17)	0.85 (0.94)	0.60	1.765	1.362
$lpha - CsPbIBr_2$ P4/mmm	0.25 (0.36)	0.11 (0.22)	0.85 (0.99)	0.63	1.550	1.402
$\alpha - CsPbIBr_2 C1$	0.26 (0.36)	0.08 (0.19)	0.89 (0.93)	0.57	1.657	1.311
$\beta - CsPbIBr_2 Fmmm$ (Equatorial)	0.17 (0.28)	0.16 (0.27)	0.93 (1.04)	0.75	1.440	1.526
β – CsPbIBr ₂ I4/mcm (Apical)	0.24 (0.35)	-0.01 (0.09)	0.85 (0.96)	0.61	1.475	1.539
α -CsPbBr ₃ <i>Pm</i> $\overline{3}m$	0.83 (0.93)	-0.02(0.06)	1.01 (1.11)	0.17	1.212	1.606

We note that this line of reasoning only applies to the well-mixed phases of the material. Higher bromine content does not, in fact, always lead to a larger gap. The calculated band gap of α -CsPbI₃ was 1.362 eV whereas α -CsPbI₂Br *P4/mmm* had a somewhat larger bandgap of 1.402 eV, and the α -CsPbI₂Br C1 cluster type (Figure 2) had a bandgap of just 1.311 eV. This can be understood by the observation that the Br-rich cluster inclusion strains the lattice and forces the Pb-I bond to be shorter than in P4/mmm, where it is allowed to relax. The bond constraint increases the VBM energy due to its antibonding (I 5p-Pb 6s) nature [64]. Our calculations confirmed this, since only the VBM shifted from 1.550 eV for P4/mmm to 1.657 eV for the C1 cluster type whereas the conduction band maximum (CBM) remained static. The latter was, however, still lower than the VBM of 1.765 eV calculated for α -CsPbI₃ *Pm3m*. All of the values for CsPbI₂Br somewhat underestimated the experimental value of 1.92 eV for CsPbI₂Br [65–67]. Our results indicated that Br-rich nanoinclusions ought to have the effect of facilitating carrier generation; however, this was likely balanced by the increased strain it applied to the lattice. Despite the soft nature of the material, the experimentally observed interface formation [23] confirmed the tendency to release this strain via segregation. It is notable that in both the cases of α -CsPbIBr₂ P4/mmm and C1, the E_{VBM} was higher than in α -CsPbI₃, which means that in a hypothetical photovoltaic device they would both donate holes to α -CsPbI₃. When analyzing the beta phases, we noted that these materials had a predicted bandgap which was somewhat wider than in the alpha-phase materials. Overall, the pristine pinning energy did not change much at all for a doping Br concentration of 33% in all cases, and the oxidation energy at the Fermi pinning energy was extremely similar for all the materials analyzed, even including α -CsPbBr₃ (Table 3).

To further analyze the redox chemistry of these materials, we calculated the CFD photooxidation reaction presented in Equation (1) by considering this reaction as a reaction of a hole-coupled iodide oxidation between a pure $3 \times 3 \times 3$ slab and a pure charged $3 \times 3 \times 3$ slab resulting in the neutral slab receiving an interstitial iodine and the charged slab gaining a halide vacancy. This process is described by the following equation:

$$E_{ox}(I_{I}^{x} + h^{\bullet}) = E(I_{I}^{x}) + E(V_{X}^{\bullet}) - \left[E(CsPbI_{2}Br)_{pure} + E(CsPbI_{2}Br^{+})_{pure}\right]$$
(9)

It is notable that the mobility of the halide vacancies allows for a halide exchange such as

$$I_{I}^{x} + h^{\bullet} \to Br_{i}^{x} + V_{I}^{\bullet}$$
⁽¹⁰⁾

There are in fact four permutations for CFDs to consider in Equation (10); namely, I_i^x/V_I^{\bullet} , I_i^x/V_{Br}^{\bullet} , Br_i^x/V_{Br}^{\bullet} and Br_i^x/V_I^{\bullet} . Two other relevant possibilities are also to be considered: the possibility of hole-free oxidation into a neutral Frenkel defect pair $X_i^{\prime}/V_X^{\bullet}$ or X_i^x/V_X^x and a Frenkel defect pair $X_i^{\bullet}/V_I^{\bullet}$ in a hole-rich regime. All of these possibilities were explored, and the results of the calculations are summarized in Table 4.

Table 4. Energies of the neutral, hole-coupled and bihole-coupled Frenkel oxidations E_{ox} for α -CsPbI₃ *Pm* $\overline{3}m$, α -CsPbI₂Br *P4/mmm* (stochastic), α -CsPbI₂Br *C1* (cluster), α -CsPbI₂Br *P4/mmm* with the coordinate system rotated by 45°, β -CsPbI₂Br *Fmmm* (equatorial) and I4/mcm (apical). We indicate negative or near-zero values with *bold* font.

	Redox Reaction:	E _{ox} (I ^x _I) (eV)	Redox Reaction	$E_{ox}(I_{I}^{x}+xh^{\bullet})$ (eV)
$\alpha - C_{s}PhI_{s}Pm\overline{3}m$	$I_{I}^{x} \rightarrow I_{i}^{x} + V_{I}^{x}$ $I^{x} \rightarrow I' + V^{\bullet}$	2.84	$I_{I}^{x} + h^{\bullet} \rightarrow I_{i}^{x} + V_{I}^{\bullet}$ $I_{i}^{x} + 2h^{\bullet} \rightarrow I^{\bullet} + V^{\bullet}$	1.25
	$\frac{\mathbf{I}_{\mathrm{I}} \rightarrow \mathbf{I}_{\mathrm{i}} + \mathbf{V}_{\mathrm{I}}}{\mathbf{I}^{\mathrm{X}} \rightarrow \mathbf{I}^{\mathrm{X}} + \mathbf{V}^{\mathrm{X}}}$	2.02	$\mathbf{I}_{\mathbf{I}}^{\mathbf{X}} + \mathbf{b}^{\bullet} \rightarrow \mathbf{I}_{\mathbf{I}}^{\mathbf{X}} + \mathbf{V}^{\bullet}$	1 21
	$I_{I} \rightarrow I_{i} + V_{I}$ $I^{X} \rightarrow I' + V^{\bullet}$	0.97	$I_{I} + I_{I} \rightarrow I_{i} + V_{I}$ $I^{X} + 2h^{\bullet} \rightarrow I^{\bullet} + V^{\bullet}$	0.46
	$Br_{n}^{x} \rightarrow Br_{i}^{x} + V_{n}^{x}$	1.65	$Br_{p}^{X} + h^{\bullet} \rightarrow Br^{X} + V_{p}^{\bullet}$	-0.02
α-CsPbI₂Br	$Br_{Br}^{X} \rightarrow Br_{i}' + V_{Br}^{\bullet}$	-0.18	$Br_{Br}^{X} + 2h^{\bullet} \rightarrow Br_{i}^{\bullet} + V_{B}^{\bullet}$	"
P4/mmm	$I_{I}^{X} \rightarrow I_{i}^{X} + V_{Br}^{X}$	2.98	$I_{I}^{x} \stackrel{DI}{+} h^{\bullet} \rightarrow I_{i}^{x} + V_{Br}^{\bullet}$	1.31
	$I_{I}^{x} \rightarrow I_{i}' + V_{Br}^{\bullet}$	1.07	$I_{I}^{x} + 2h^{\bullet} \rightarrow I_{i}^{\bullet} + V_{Br}^{\bullet}$	0.56
	$Br_{Br}^{x} \rightarrow Br_{i}^{x} + V_{I}^{x}$	1.59	$Br_{Br}^{x} + h^{\bullet} \rightarrow Br_{i}^{x} + V_{I}^{\bullet}$	-0.12
	${ m Br}_{{ m Br}}^{ m x} ightarrow { m Br}_{ m i}^{\prime} + { m V}_{ m I}^{ullet}$	-0.27	$Br_{Br}^{x} + 2h^{\bullet} \rightarrow Br_{i}^{\bullet} + V_{I}^{\bullet}$	-0.10
	$I_{I}^{x} \rightarrow I_{i}^{x} + V_{I}^{x} \label{eq:eq:expansion}$	1.73	$I_I^x + h^\bullet \to I_i^x + V_I^\bullet$	0.39
	$\mathrm{I}_{\mathrm{I}}^{\mathrm{x}} \to \mathrm{I}_{\mathrm{i}}' + \mathrm{V}_{\mathrm{I}}^{\bullet}$	-0.26	$I_I^x + 2h^{ullet} ightarrow I_i^{ullet} + V_I^{ullet}$	0.07
	$Br_{Br}^{X} \rightarrow Br_{i}^{X} + V_{Br}^{X}$	1.93	$Br_{Br}^{X} + h^{\bullet} \rightarrow Br_{i}^{X} + V_{Br}^{\bullet}$	0.80
α -CsPbI ₂ Br	$Br_{Br}^{X} \rightarrow Br_{i}' + V_{Br}^{\bullet}$	0.69	$\operatorname{Br}_{\operatorname{Br}}^{x} + 2h^{\bullet} \to \operatorname{Br}_{i}^{\bullet} + \operatorname{V}_{\operatorname{Br}}^{\bullet}$	r 0.96
C1	$I_{I}^{\lambda} \rightarrow I_{i}^{\lambda} + V_{Br}^{\lambda}$	2.29	$l_{I}^{\Lambda} + h^{\bullet} \rightarrow l_{i}^{\Lambda} + V_{Br}^{\bullet}$	1.16
	$I_{I}^{T} \rightarrow I_{i} + V_{Br}$ $Br^{X} \rightarrow Br^{X} + V^{X}$	0.51	$I_{I}^{T} + 2n \rightarrow I_{i} + V_{Br}$ $Br^{X} + b^{\bullet} \rightarrow Br^{X} + V^{\bullet}$	0.84
	$\text{Br}_{\text{Br}} \rightarrow \text{Br}_{i} + \text{V}_{I}$ $\text{Br}^{\text{X}} \rightarrow \text{Br}' + \text{V}^{\bullet}$	1.57 0.08	$\operatorname{Dr}_{\operatorname{Br}}^{r} + \operatorname{Ir} \to \operatorname{Dr}_{i}^{r} + \operatorname{V}_{I}^{r}$ $\operatorname{Br}^{x} + 2\mathbf{b}^{\bullet} \to \operatorname{Br}^{\bullet} + \operatorname{V}^{\bullet}$	0.03
	$DI_{Br} \rightarrow DI_i + V_I$	-0.00	$DI_{Br} + 2II \rightarrow DI_{i} + V_{I}$	0.19
	$l_{I}^{\star} \rightarrow l_{i}^{\star} + V_{I}^{\star}$	0.45	$l_{I}^{\star} + h^{\bullet} \rightarrow l_{i}^{\star} + V_{I}^{\bullet}$	-1.24
	$I_{I}^{T} \rightarrow I_{i} + V_{I}$ $B_{r}^{X} \rightarrow B_{r}^{X} + V^{X}$	-2.06	$I_{I}^{T} + 2n \rightarrow I_{i} + V_{I}$ $Br^{X} + b^{\bullet} \rightarrow Br^{X} + V^{\bullet}$	-1.76
~ -CePhI_Br	$Br_{Br} \rightarrow Dr_i + V_{Br}$ $Br^{X} \rightarrow Br' + V^{\bullet}$	0.54 _1 3/	$\operatorname{Br}^{X} + \operatorname{Ir} \to \operatorname{Dr}_{i} + \operatorname{V}_{Br}$ $\operatorname{Br}^{X} + 2\mathbf{b}^{\bullet} \to \operatorname{Br}^{\bullet} + \operatorname{V}^{\bullet}$	-1.19
P4/mmm(rc)	$I_{Br}^{x} \rightarrow I_{i}^{x} + V_{Br}^{x}$	1.04	$I_{Br}^{x} + h^{\bullet} \rightarrow I_{i}^{x} + V_{P}^{\bullet}$	-0.51
r r/ minin (rc)	$I_{I}^{X} \rightarrow I_{I}' + V_{P_{I}}^{\bullet}$	-1.34	$I_{I}^{X} + 2h^{\bullet} \rightarrow I_{I}^{\bullet} + V_{P}^{\bullet}$	-1.03
	$Br_{Br}^{\chi} \rightarrow Br_{i}^{\chi} + V_{I}^{\chi}$	-0.23	$\operatorname{Br}_{\operatorname{Br}}^{X} + \operatorname{h}^{\bullet} \to \operatorname{Br}_{\operatorname{i}}^{X} + \operatorname{V}_{\operatorname{I}}^{\bullet}$	-1.92
	$\mathrm{Br}_{\mathrm{Br}}^{\mathrm{X}} ightarrow \mathrm{Br}_{\mathrm{i}}' + \mathrm{V}_{\mathrm{I}}^{\bullet}$	-2.07	$Br_{Br}^{X} + 2h^{\bullet} \rightarrow Br_{i}^{\bullet} + V_{I}^{\bullet}$	-1.76
	$I_{I}^{x} \rightarrow I_{i}^{x} + V_{I}^{x}$	3.57	$I_I^x + h^\bullet \to I_i^x + V_I^\bullet$	1.73
	$I_{I}^{x} \rightarrow I_{i}^{\prime} + V_{I}^{\bullet}$	1.85	$I_{I}^{x} + 2h^{\bullet} \rightarrow I_{i}^{\bullet} + V_{I}^{\bullet}$	0.75
	$Br_{Br}^{x} \rightarrow Br_{i}^{x} + V_{Br}^{x}$	3.40	$Br_{Br}^{x} + h^{\bullet} \rightarrow Br_{i}^{x} + V_{Br}^{\bullet}$	1.58
β -CsPbI ₂ Br	$Br_{Br}^{X} \rightarrow Br_{i}' + V_{Br}^{\bullet}$	1.51	$Br_{Br}^{x} + 2h^{\bullet} \rightarrow Br_{i}^{\bullet} + V_{B}^{\bullet}$	r 1.68
Fmmm(Equatorial)	$l_{I}^{x} \rightarrow l_{i}^{x} + V_{Br}^{x}$	4.03	$l_{I}^{x} + h^{*} \rightarrow l_{i}^{x} + V_{Br}$	2.21
	$I_{I}^{\star} \rightarrow I_{i}^{\prime} + V_{Br}^{\bullet}$	2.33	$I_{I}^{\Lambda} + 2h^{\bullet} \rightarrow I_{i}^{\bullet} + V_{Br}^{\bullet}$	1.22
	$\text{Br}_{\text{Br}}^{n} \rightarrow \text{Br}_{i}^{n} + V_{I}^{n}$	2.94	$Br_{Br}^{A} + h \rightarrow Br_{i}^{A} + V_{I}^{\bullet}$ $Pr^{X} + 2h^{\bullet} \rightarrow Pr^{\bullet} + V^{\bullet}$	1.11 1.21
	$\text{Dr}_{\text{Br}} \rightarrow \text{Dr}_{\text{i}} + \text{v}_{\text{I}}$	1.04	$\text{Dr}_{\text{Br}} + 2n \rightarrow \text{Dr}_{i} + \text{v}_{I}$	1.21
β-CsPbI ₂ Br I4/mcm(Apical)	$I_{I}^{\wedge} \rightarrow I_{i}^{\wedge} + V_{I}^{\wedge}$	1.25	$I_{I}^{A} + h^{\bullet} \rightarrow I_{i}^{A} + V_{I}^{\bullet}$	-1.29
	$\mathbf{I}_{\bar{\mathbf{I}}}^{r} \rightarrow \mathbf{I}_{\bar{\mathbf{I}}} + \mathbf{V}_{\bar{\mathbf{I}}}^{r}$ $\mathbf{Br}^{X} \rightarrow \mathbf{Br}^{X} + \mathbf{V}^{X}$	-1.37	$I_{I} + 2n \rightarrow I_{i} + V_{I}$ $Br^{X} \pm b^{\bullet} \propto Br^{X} \pm V^{\bullet}$	-1.10
	$Br_{Br}^{X} \rightarrow Br'_{i} + V^{\bullet}$	- 1 60	$Br_{Br}^{r} + 10 \rightarrow Dr_{i}^{r} + V_{Br}^{r}$ $Br_{i}^{r} + 2b^{\bullet} \rightarrow Br^{\bullet} + V^{\bullet}$	-1.43 -1.34
	$I_{Br}^{x} \rightarrow I_{i}^{x} + V_{Br}^{x}$	1.31	$J_{Br}^{x} + h^{\bullet} \rightarrow I_{i}^{x} + V_{p}^{\bullet}$	-0.49
	$I_{I}^{X} \rightarrow I_{i}^{\prime} + V_{P}^{Br}$	-0.58	$I_{I}^{x} + 2h^{\bullet} \rightarrow I^{\bullet} + V_{P}^{\bullet}$	-0.37
	$\operatorname{Br}_{\operatorname{Br}}^{X} \to \operatorname{Br}_{i}^{X} + \operatorname{V}_{\tau}^{X}$	0.31	$\operatorname{Br}_{\operatorname{Br}}^{X} + \operatorname{h}^{\bullet} \to \operatorname{Br}_{i}^{X} + \operatorname{V}_{\tau}^{\bullet}$	-2.22
	$\mathrm{Br}_{\mathrm{Br}}^{\overset{\mathrm{J}}{\mathrm{X}}} ightarrow \mathrm{Br}_{\mathrm{i}}^{\prime} + \mathrm{V}_{\mathrm{I}}^{\overset{\mathrm{I}}{\mathrm{\bullet}}}$	-2.40	$Br_{Br}^{X^{i}} + 2h^{\bullet} \rightarrow Br_{i}^{i} + V_{I}^{\bullet}$	-2.13



Figure 6. The partial density of states of (**a**). α -CsPbI₃ P4/*mmm* and (**b**). α -CsPbI₃ C1 (cluster type).

It can be seen from these results that α -CsPbI₂Br *P4/mmm* only showed instability towards hole-free CFDs involving bromine, either with bromine or iodine vacancies, indicating a lack of thermodynamic preference for vacancy type. Meanwhile, the α -CsPbI₂Br *C1* phase showed instability towards the hole-free I'_i/V[•]₁ CFD, further supporting the destabilizing strain effects a bromine-rich nanoinclusion has on the surrounding CsPbI₃; however, it appears that the inclusion was also somewhat destabilized since the hole-free Br'_i/V[•]₁ CFD pair also had a low E_{ox}. In the case of all α -CsPbI₂Br phases, we noted that only hole-coupling and two-hole-coupled and two-hole-coupled I^x_i/V[•]₁ pairs were also much more destabilized when compared to α -CsPbI₂Br *P4/mmm*.

One mechanism by which the phase transformation of an a-phase perovskite to a b-phase perovskite can take place is a defect-coupled process where PbX₆ octahedra are allowed to release lattice strain through rotation in relation to one another (Figure 4). To test this hypothesis, we considered the α -CsPbI₂Br *P4/mmm* phase of the material (Table 4), but with the coordinate system rotated by 45° around the *c*-axis, thus aligning its coordinate system with that of the β -CsPbI₂Br phases. The hypothesis was confirmed since the material retained its character in the defect-free supercell, but as soon as vacancies or interstitials were introduced there was a clear rotation of the octahedra, and a *b*-phase emerged. Thus, our

results strongly support this hypothesis and suggest that α -CsPbI₂Br may be unstable not just because it can segregate, but also because it will transform into β -CsPbI₂Br upon accumulation of CFD defects. We note the extremely favorable nature of CFD formation in the rotated α -CsPbI₂Br P4/mmm phase is indicative of the thermodynamic favorability of this process.

In the case of β -CsPbI₂Br, we observed a very different behavior where the equatorial *Fmmm* phase was stable towards all pathways of oxidation considered and the apical one was highly unstable towards all mechanisms involving either charged defects or hole coupling. This indicates that the *Fmmm* phase is not only much more resilient towards segregating into CsPbI₃/CsPbBr₃, but it will also generate far fewer CFDs upon light exposure. We conclude this section with a DFT-based prediction that the selective preparation of β -CsPbI₂Br *Fmmm* should yield a significantly more stable mixed material; however, if one assumes that it occurs from the defect-coupled rotations of octahedra in α -CsPbIBr₂ *P4/mmm*, then it is unlikely that β -CsPbI₂Br *Fmmm* could be easily and selectively prepared. A visual analysis of the results of our defect calculations confirmed as much (Figures 7 and S9 of SI). In conclusion, we stress the most important result of this section, which is that β -CsPbI₂Br *Fmmm* has photostability far superior to any phase of α -CsPbI₂Br and, surprisingly, it is even superior to α -CsPbI₃. The engineering of such a highly stable phase might be combined with other strategies such as nonstoichiometry [68] or the release of microstrain [69] to achieve a superior perovskite-based photovoltaic material.



Figure 7. α -CsPbI₂Br *P4/mmm* with a rotated coordinate system to align with β -CsPbI₂Br and the same lattice with iodine and bromine interstitials.

4. Conclusions

The straightforward logic of why one ought to mix the superior photovoltaic properties of CsPbI₃ with the increased stability of CsPbBr₃ seems quite at odds with how difficult it is to understand why such materials are unstable. Even a conservative amount of bromine additive greatly changes the photochemistry of the material. Bromine-rich nanoinclusions of CsPbBr₃ into α -CsPbI₂Br leave it more susceptible to oxidation via charged Frenkel defect pairs. Even worse, the formation of these charged vacancy and interstitial defect pairs outright destabilizes the pseudocubic phase and allows the PbX_6 octahedra to rotate into β -CsPbI₂Br. Further complications arise from the fact that β -CsPbI₂Br has two phases which are quite different in their resilience against CFD formation and photo segregation. In the present study, we found that the equatorial phase appeared to be very stable as a mixed solid solution and was resilient against CFD formation, whereas the apical phase was highly vulnerable to CFD formation and had a much higher mixing energy. This major difference in mixing energies implies that the material is likely capable of assuming the equatorial phase selectively, which means that selectively isolating the phase is a very real possibility in expanding the material scientist's toolbox in engineering a stable perovskite photovoltaic cell. Given that the band gap seems to be somewhat wider for this phase than for the α -CsPbI₂Br phase, we have to conclude that the equatorial β -CsPbI₂Br is ultimately a compromise of some photovoltaic performance in favor of photostability. An additional potential difficulty is seen in the mechanism by which theory predicts the formation of such a phase: it originates from the rotations of PbX₆ octahedra in α -CsPbI₂Br, and thus a complex scheme might be necessary for successfully isolating this phase. Our calculations suggest that an experimental synthesis of the promising equatorial β -CsPbI₂Br should probably bypass all α -CsPbI₂Br phases to avoid random rotations into various β -CsPbI₂Br phases.

Supplementary Materials: The following supporting information can be downloaded at: https:// www.mdpi.com/article/10.3390/nano13020276/s1, Figure S1: Energy versus volume (EV) curves, Figure S2: Density of states and band structure of β -CsPbI2Br with apical and equatorial phases, Figure S3: Density of states and band structure of β -CsPbI2Br *C1* and α -CsPbI3 *P4/mmm* (rotated coordinates), Figure S4: Partial DOS of α -CsPb(I_{1-x}Br_x)₃ x = 0,1/3,1/6, Figure S5: pDOS of α -CsPb(I_{1-x}Br_x)₃ x = 1/2,2/3,5/6, Figure S6: Partial DOS of β -CsPb(I_{1-x}Br_x)₃ x = 0,1/3,1/6, Figure S7: pDOS of β -CsPb(I_{1-x}Br_x)₃ x = 1/2,2/3,5/6, Figure S8: pDOS of β -CsPb(I_{1-x}Br_x)₃ x = 1/2,2/3,5/6, partial DOS of α -CsPbBr₃ and β -CsPbBr₃, Figure S9: Geometrical distortions of α -CsPbI2Br *P4/mmm*.

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Abbreviations

DFT	Density functional theory
GGA	Generalized gradient approximation
MGGA	Metageneralized gradient approximation
VASP	Vienna Ab initio Simulation Package
PAW	Projector augmented-wave
PV	Photovoltaic
PCE	Photoconversion efficiency
CFD	Charged Frenkel defect
SOC	Spin–orbit coupling
EOS	Equation of state
DOS	Density of states
pDOS	Partial density of states
EV	Energy versus volume

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